TITLE:

DECLARATION

Att: Docket No. <u>8836-143 (IB11007-US)</u>

AS A BELOW NAMED INVENTOR, I hereby declare that:

My residence, post office address and citizenship are as stated next to my name.

I believe that I am the original, first and sole (if only one name is listed below), or an original, first and joint inventor (if plural names are listed below), of the subject matter which is claimed and for which a patent is sought on the invention entitled:

METHOD AND DEVICE FOR PROGRAMMING NONVOLATILE SEMICONDUCTOR MEMORY

the specification of which either i	s-attached hereto or indicates an	attorney docket no. <u>8836-143 (IB110</u>	07-US), or	:
☐ was filed in the U.S. Patent &	Trademark Office on	and assigned Serial No.	,	
and (if applicable) was amend	ded on		,	
claims, as amended by any amend to patentability and to the examina I hereby claim foreign priority ben or inventor's certificate, or §365(a	dment referred to above. I acknowlition of this application in accordate effits under Title 35, U.S. Code §1 a) of any PCT international applitue also identified below any force.	ontents of the above-identified specific owledge the duty to disclose information ance with Title 37 of the Code of Federa 19(a)-(d) or §365(b) of any foreign apportation which designated at least one coding applications for patent or inventor med:	on which is il Regulatio lication(s) in ountry other	material ns §1.56. for patent r than the
ill	mount on which priority to cras		Priority (<u>Claimed:</u>
2001-20764 (Application Number)	Korea (Country)	18 April 2001 (Day/Month/Year filed)	_ Yes [X]	No []
= = 			_ Yes []	No []
(Application Number)	(Country)	(Day/Month/Year filed)	[]	- · · · []
States provisional application(s), and, insofar as the subject matter International application(s) in the totalisclose information material to	or §365(c) of any PCT Internation of each of the claims of this appropriate provided by the first parapatentability as defined in Title 3	fany United States application(s), or § nal application designating the United lication is not disclosed in the prior Ugraph of Title 35, U.S. Code, §112, I at 7, The Code of Federal Regulations, §1 ational or PCT international filing date	States, list Inited State eknowledge 56(a) which	ed below s or PCT the duty
(Application Serial Number)	(Filing Date)	(STATUS: patented, pending,	abandoned)	
(Application Serial Number)	(Filing Date)	(STATUS: patented, pending,	abandoned)	

I hereby appoint the following attorneys: **FRANK CHAU**, Reg. No. 34,136; and **JAMES J. BITETTO**, Reg. No. 40,513; **FRANK V. DeROSA**, Reg. No. 43,584; **GASPARE J. RANDAZZO**, Reg. No. 41,528; **SUSAN PAIK**, Reg. No. 46,347; and **JUAN C. VILLAR**, Reg. No. 34,271; each of them of **F. CHAU & ASSOCIATES, LLP**, 1900 Hempstead Turnpike, Suite 501, East Meadow, New York 11554 to prosecute this application and to transact all business in the U.S. Patent and Trademark Office connected therewith and with any divisional, continuation, continuation-in-part, reissue or reexamination application, with full power of appointment and with full power to substitute an associate attorney or agent, and to receive all patents which may issue thereon, and request that all correspondence be addressed to:

Frank Chau, Esq. F. CHAU & ASSOCIATES, LLP 1900 Hempstead Turnpike, Suite 501 East Meadow, New York 11554 Area Code: 516-357-0091 I HEREBY DECLARE that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under §1001 of Title 18 U.S. Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

FULL NAME OF FIRST OR SOLE	Citizenship <u>Korea</u>	
Inventor's signature:	Jong-Keun AMN	Date: 27 Sep. 200 /
Residence & Post Office Address:	411-406, Kayang Apt., Kayang-dong, Kangseo-ku, Seoul, Republic of Korea	
	VTOR:	
FULL NAME OF SECOND-INVEN	Citizenship	
Inventor's signature:		
FUL NAME OF THIRD INVENT	OR:	Citizenship
. 75		Date:
Residence & Post Office Address:		
FULL NAME OF FOURTH INVEN	Citizenship	
Inventor's signature:	Date:	
Residence & Post Office Address:		

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